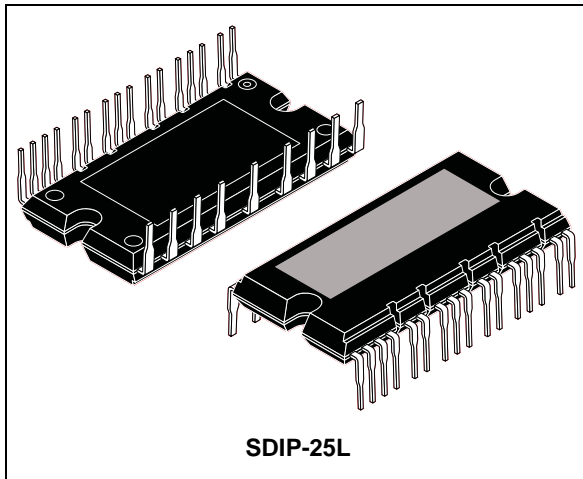


## SLLIMM™ small low-loss intelligent molded module IPM, 3-phase inverter - 20 A, 600 V short-circuit rugged IGBT

Datasheet - production data



### Applications

- 3-phase inverters for motor drives
- Air conditioners

### Description

This intelligent power module provides a compact, high performance AC motor drive in a simple, rugged design. Combining ST proprietary control ICs with the most advanced short-circuit-rugged IGBT system technology, this device is ideal for 3-phase inverters in applications such as motor drives and air conditioners. SLLIMM™ is a trademark of STMicroelectronics.

### Features

- IPM 20 A, 600 V 3-phase IGBT inverter bridge including control ICs for gate driving and free-wheeling diodes
- Short-circuit rugged IGBTs
- 3.3 V, 5 V, 15 V CMOS/TTL inputs comparators with hysteresis and pull-down / pull-up resistors
- Undervoltage lockout
- Internal bootstrap diode
- Interlocking function
- Shutdown function
- 4.7 kΩ NTC for temperature control
- DBC leading to low thermal resistance
- Isolation rating of 2500 V<sub>rms</sub>/min
- UL recognized: UL1557 file E81734

**Table 1. Device summary**

| Order code     | Marking      | Package  | Packing |
|----------------|--------------|----------|---------|
| STGIPS20C60T-H | GIPS20C60T-H | SDIP-25L | Tube    |

# Contents

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# 1 Internal block diagram and pin configuration

Figure 1. Internal block diagram

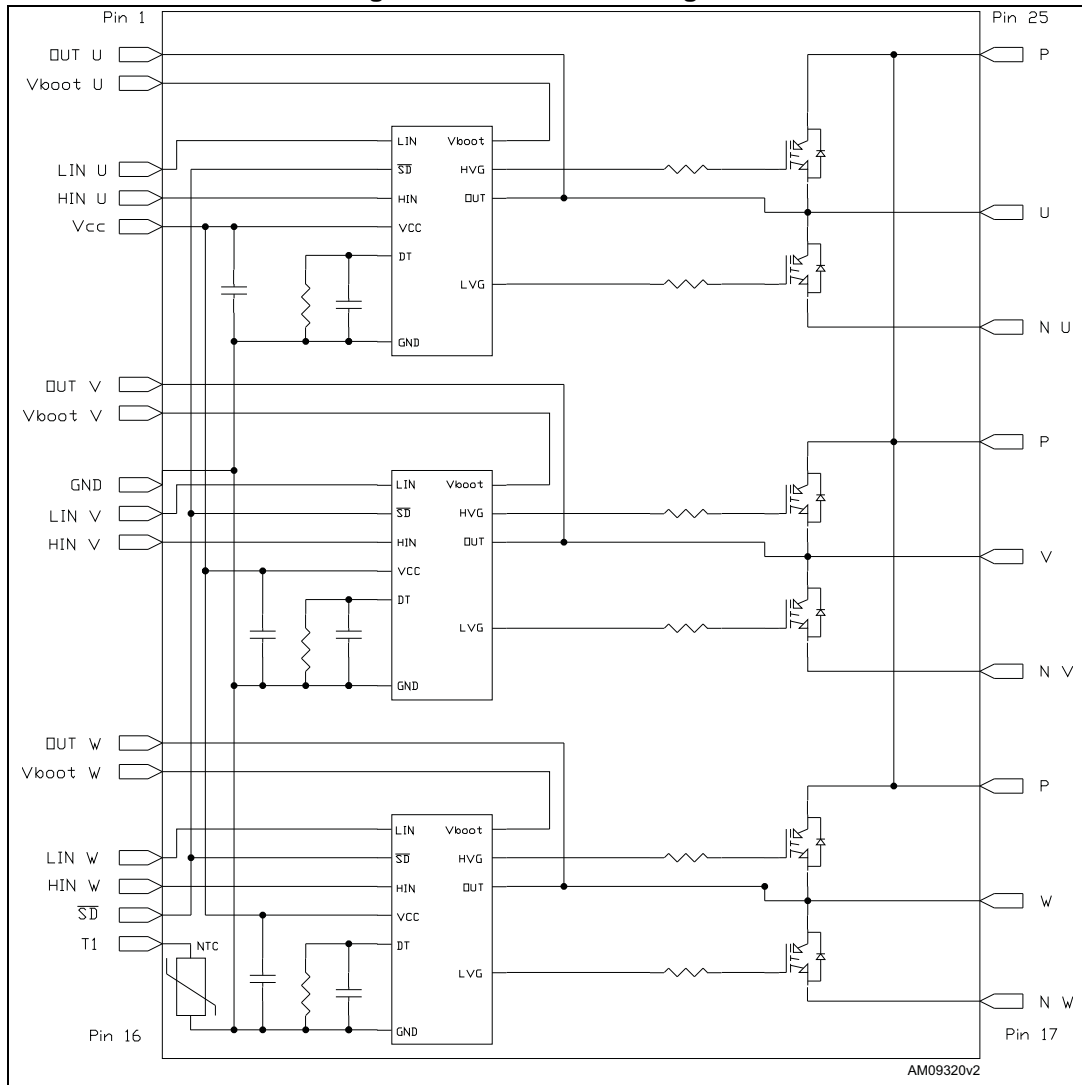
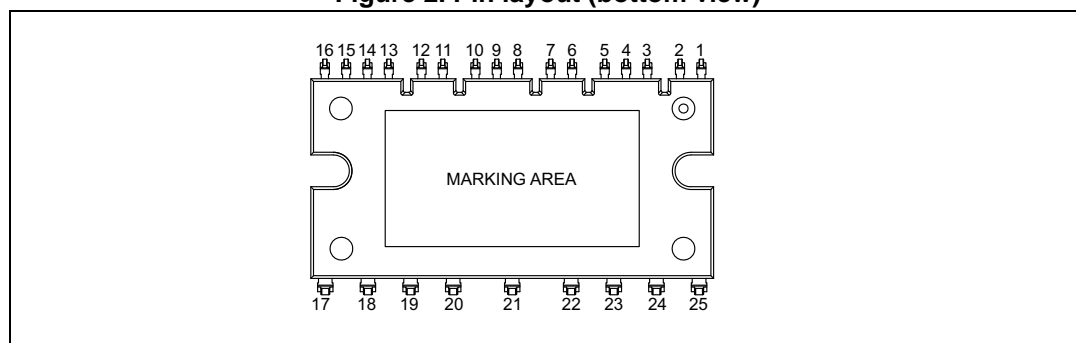


Table 2. Pin description

| Pin n° | Symbol              | Description                            |
|--------|---------------------|--|
| 1      | OUT <sub>U</sub>    | High-side reference output for U phase |
| 2      | V <sub>bootU</sub>  | Bootstrap voltage for U phase          |
| 3      | LIN <sub>U</sub>    | Low-side logic input for U phase       |
| 4      | HIN <sub>U</sub>    | High-side logic input for U phase      |
| 5      | V <sub>CC</sub>     | Low voltage power supply               |
| 6      | OUT <sub>V</sub>    | High-side reference output for V phase |
| 7      | V <sub>boot V</sub> | Bootstrap voltage for V phase          |
| 8      | GND                 | Ground                                 |
| 9      | LIN <sub>V</sub>    | Low-side logic input for V phase       |
| 10     | HIN <sub>V</sub>    | High-side logic input for V phase      |
| 11     | OUT <sub>W</sub>    | High-side reference output for W phase |
| 12     | V <sub>boot W</sub> | Bootstrap voltage for W phase          |
| 13     | LIN <sub>W</sub>    | Low-side logic input for W phase       |
| 14     | HIN <sub>W</sub>    | High-side logic input for W phase      |
| 15     | $\overline{SD}$     | Shutdown logic input (active low)      |
| 16     | T1                  | NTC thermistor terminal                |
| 17     | N <sub>W</sub>      | Negative DC input for W phase          |
| 18     | W                   | W phase output                         |
| 19     | P                   | Positive DC input                      |
| 20     | N <sub>V</sub>      | Negative DC input for V phase          |
| 21     | V                   | V phase output                         |
| 22     | P                   | Positive DC input                      |
| 23     | N <sub>U</sub>      | Negative DC input for U phase          |
| 24     | U                   | U phase output                         |
| 25     | P                   | Positive DC input                      |

Figure 2. Pin layout (bottom view)



## 2 Electrical ratings

### 2.1 Absolute maximum ratings

Table 3. Inverter part

| Symbol             | Parameter   | Value | Unit          |
|--------------------|---|-------|---------------|
| $V_{PN}$           | Supply voltage applied between P - $N_U$ , $N_V$ , $N_W$  | 450   | V             |
| $V_{PN(surge)}$    | Supply voltage (surge) applied between P - $N_U$ , $N_V$ , $N_W$  | 500   | V             |
| $V_{CES}$          | Each IGBT collector emitter voltage ( $V_{IN}^{(1)} = 0$ )  | 600   | V             |
| $\pm I_C$          | Each IGBT continuous collector current at $T_C = 25^\circ\text{C}$  | 20    | A             |
| $\pm I_{CP}^{(2)}$ | Each IGBT pulsed collector current  | 40    | A             |
| $P_{TOT}$          | Each IGBT total dissipation at $T_C = 25^\circ\text{C}$   | 46    | W             |
| $t_{scw}$          | Short circuit withstand time, $V_{CE} = 0.5 V_{(BR)CES}$<br>$T_J = 125^\circ\text{C}$ , $V_{CC} = V_{boot} = 15\text{ V}$ , $V_{IN}^{(1)} = 0 - 5\text{ V}$ | 5     | $\mu\text{s}$ |

1. Applied between  $HIN_i$ ,  $LIN_i$  and GND for  $i = U, V, W$
2. Pulse width limited by max junction temperature

Table 4. Control part

| Symbol        | Parameter   | Value                               | Unit |
|---------------|---|-------------------------------------|------|
| $V_{OUT}$     | Output voltage applied between $OUT_U$ , $OUT_V$ , $OUT_W$ - GND          | $V_{boot} - 21$ to $V_{boot} + 0.3$ | V    |
| $V_{CC}$      | Low voltage power supply  | - 0.3 to +21                        | V    |
| $V_{boot}$    | Bootstrap voltage applied between $V_{boot\ i} - OUT_i$ for $i = U, V, W$ | - 0.3 to 620                        | V    |
| $V_{IN}$      | Logic input voltage applied between $HIN$ , $LIN$ and GND                 | - 0.3 to 15                         | V    |
| $V_{SD/OD}$   | Open drain voltage  | - 0.3 to 15                         | V    |
| $dV_{OUT}/dt$ | Allowed output slew rate  | 50                                  | V/ns |

Table 5. Total system

| Symbol    | Parameter   | Value       | Unit             |
|-----------|---|-------------|------------------|
| $V_{ISO}$ | Isolation withstand voltage applied between each pin and heatsink plate (AC voltage, $t = 60\text{ sec.}$ ) | 2500        | V                |
| $T_j$     | Power chips operating junction temperature  | - 40 to 150 | $^\circ\text{C}$ |
| $T_C$     | Module case operation temperature   | - 40 to 125 | $^\circ\text{C}$ |

## 2.2 Thermal data

Table 6. Thermal data

| Symbol     | Parameter                                     | Value | Unit |
|------------|---|-------|------|
| $R_{thJC}$ | Thermal resistance junction-case single IGBT  | 2.7   | °C/W |
|            | Thermal resistance junction-case single diode | 5     | °C/W |

Figure 3. Maximum  $I_{C(RMS)}$  current vs. switching frequency (1)

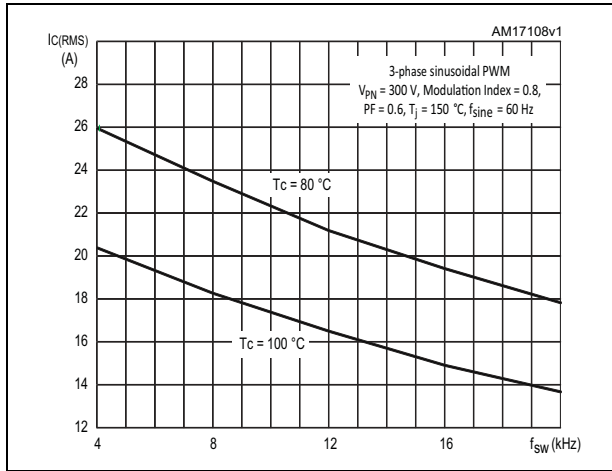
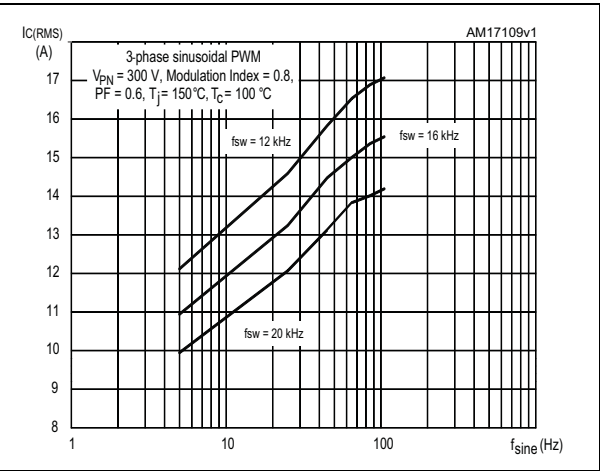


Figure 4. Maximum  $I_{C(RMS)}$  current vs.  $f_{sine}$  (1)



1. Simulated curves refer to typical IGBT parameters and maximum  $R_{thj-c}$ .

### 3 Electrical characteristics

$T_J = 25\text{ °C}$  unless otherwise specified.

**Table 7. Inverter part**

| Symbol  | Parameter  | Test conditions  | Value |      |      | Unit          |
|---|--|--|-------|------|------|---------------|
|   |  |  | Min.  | Typ. | Max. |               |
| $V_{CE(sat)}$                                   | Collector-emitter saturation voltage                             | $V_{CC} = V_{boot} = 15\text{ V}$ , $V_{IN}^{(1)} = 0 \div 5\text{ V}$ ,<br>$I_C = 20\text{ A}$  | -     | 1.6  | 2    | V             |
|   |  | $V_{CC} = V_{boot} = 15\text{ V}$ , $V_{IN}^{(1)} = 0 \div 5\text{ V}$ ,<br>$I_C = 20\text{ A}$ , $T_J = 125\text{ °C}$  | -     | 1.7  |      |               |
| $I_{CES}$                                       | Collector-cut off current<br>( $V_{IN}^{(1)} = 0$ "logic state") | $V_{CE} = 550\text{ V}$ , $V_{CC} = V_{Boot} = 15\text{ V}$  | -     |      | 100  | $\mu\text{A}$ |
| $V_F$   | Diode forward voltage  | $V_{IN}^{(1)} = 0$ "logic state", $I_C = 20\text{ A}$  | -     |      | 2.2  | V             |
| <b>Inductive load switching time and energy</b> |  |  |       |      |      |               |
| $t_{on}$  | Turn-on time   | $V_{PN} = 300\text{ V}$ ,<br>$V_{CC} = V_{boot} = 15\text{ V}$ ,<br>$V_{IN}^{(1)} = 0 \div 5\text{ V}$ ,<br>$I_C = 20\text{ A}$<br>(see <a href="#">Figure 5</a> ) | -     | 390  | -    | ns            |
| $t_{c(on)}$                                     | Crossover time (on)  |  | -     | 170  | -    |               |
| $t_{off}$                                       | Turn-off time  |  | -     | 970  | -    |               |
| $t_{c(off)}$                                    | Crossover time (off)   |  | -     | 150  | -    |               |
| $t_{rr}$  | Reverse recovery time  |  | -     | 284  | -    | $\mu\text{J}$ |
| $E_{on}$  | Turn-on switching losses   |  | -     | 520  | -    |               |
| $E_{off}$                                       | Turn-off switching losses  |  | -     | 460  | -    |               |

1. Applied between  $HIN_i$ ,  $LIN_i$  and GND for  $i = U, V, W$ .

Note:  $t_{ON}$  and  $t_{OFF}$  include the propagation delay time of the internal drive.  $t_{C(ON)}$  and  $t_{C(OFF)}$  are the switching time of IGBT itself under the internally given gate driving condition.

Figure 5. Switching time test circuit

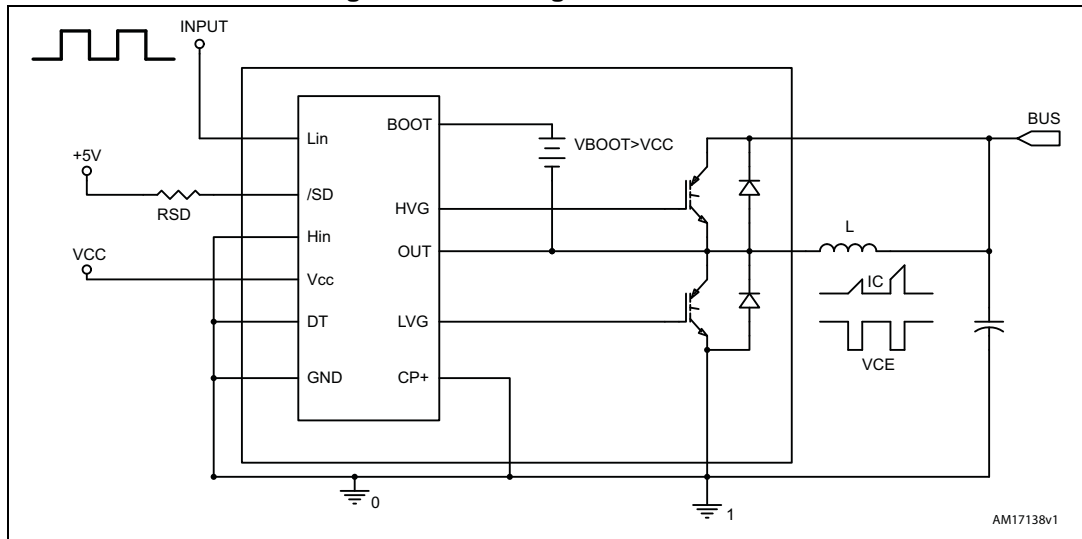


Figure 6. Switching time definition

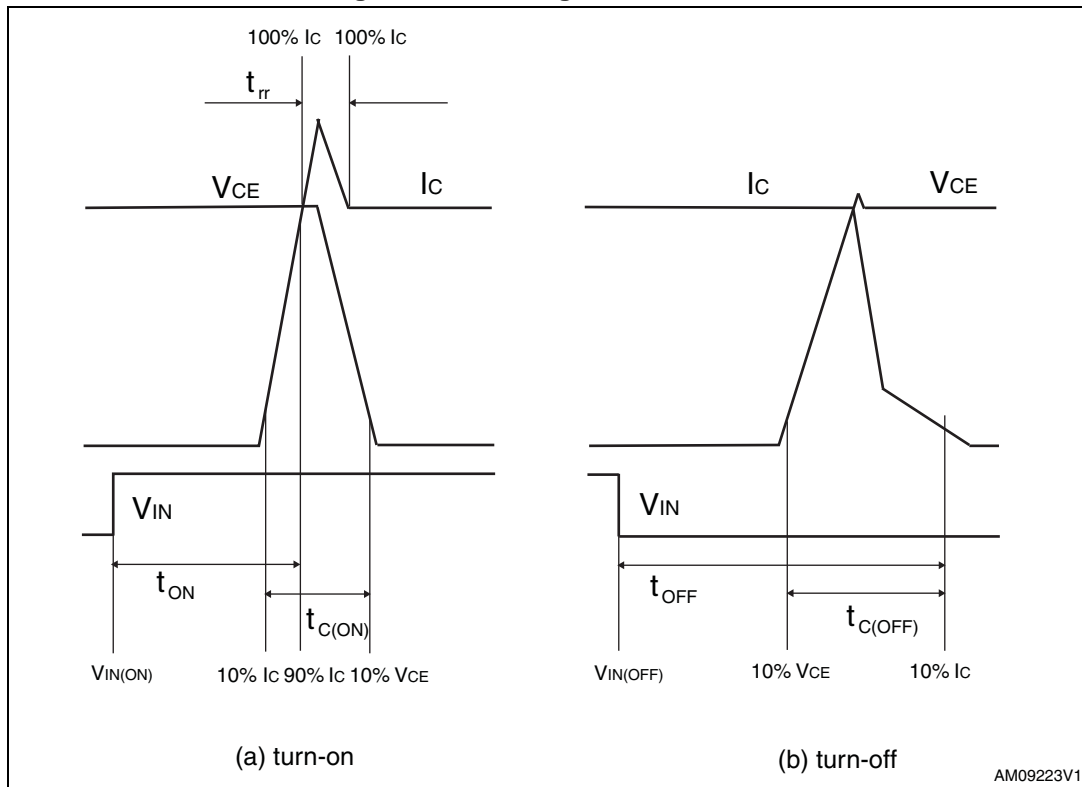


Figure 4 "Switching time definition" refers to HIN, LIN inputs (active high).



### 3.1 Control part

**Table 8. Low voltage power supply ( $V_{CC} = 15\text{ V}$  unless otherwise specified)**

| Symbol          | Parameter                             | Test conditions   | Min. | Typ. | Max. | Unit          |
|-----------------|---------------------------------------|---|------|------|------|---------------|
| $V_{CC\_hys}$   | $V_{CC}$ UV hysteresis                |   | 1.2  | 1.5  | 1.8  | V             |
| $V_{CC\_thON}$  | $V_{CC}$ UV turn ON threshold         |   | 11.5 | 12   | 12.5 | V             |
| $V_{CC\_thOFF}$ | $V_{CC}$ UV turn OFF threshold        |   | 10   | 10.5 | 11   | V             |
| $I_{qccu}$      | Undervoltage quiescent supply current | $V_{CC} = 10\text{ V}$<br>$\overline{SD} = 5\text{ V}; LIN = HIN = 0$ |      |      | 450  | $\mu\text{A}$ |
| $I_{qcc}$       | Quiescent current                     | $V_{CC} = 15\text{ V}$<br>$\overline{SD} = 5\text{ V}; LIN = HIN = 0$ |      |      | 3.5  | mA            |

**Table 9. Bootstrapped voltage ( $V_{CC} = 15\text{ V}$  unless otherwise specified)**

| Symbol          | Parameter                               | Test conditions   | Min. | Typ. | Max. | Unit          |
|-----------------|---|---|------|------|------|---------------|
| $V_{BS\_hys}$   | $V_{BS}$ UV hysteresis                  |   | 1.2  | 1.5  | 1.8  | V             |
| $V_{BS\_thON}$  | $V_{BS}$ UV turn ON threshold           |   | 11.1 | 11.5 | 12.1 | V             |
| $V_{BS\_thOFF}$ | $V_{BS}$ UV turn OFF threshold          |   | 9.8  | 10   | 10.6 | V             |
| $I_{QBSU}$      | Undervoltage $V_{BS}$ quiescent current | $V_{BS} < 9\text{ V}$<br>$\overline{SD} = 5\text{ V}; LIN = 0, HIN = 5\text{ V}$  |      | 70   | 110  | $\mu\text{A}$ |
| $I_{QBS}$       | $V_{BS}$ quiescent current              | $V_{BS} = 15\text{ V}$<br>$\overline{SD} = 5\text{ V}; LIN = 0, HIN = 5\text{ V}$ |      | 200  | 300  | $\mu\text{A}$ |
| $R_{DS(on)}$    | Bootstrap driver on resistance          | $LIN = 5\text{ V}; HIN = 0\text{ V}$  |      | 120  |      | $\Omega$      |

**Table 10. Logic inputs ( $V_{CC} = 15\text{ V}$  unless otherwise specified)**

| Symbol     | Parameter                                    | Test conditions   | Min. | Typ. | Max. | Unit          |
|------------|--|---|------|------|------|---------------|
| $V_{il}$   | Low level logic threshold voltage            |   | 0.8  |      | 1.1  | V             |
| $V_{ih}$   | High level logic threshold voltage           |   | 1.9  |      | 2.25 | V             |
| $I_{HINh}$ | HIN logic "1" input bias current             | $HIN = 15\text{ V}$                                       | 20   | 40   | 100  | $\mu\text{A}$ |
| $I_{HINI}$ | HIN logic "0" input bias current             | $HIN = 0\text{ V}$  |      |      | 1    | $\mu\text{A}$ |
| $I_{LINh}$ | LIN logic "1" input bias current             | $LIN = 15\text{ V}$                                       | 20   | 40   | 100  | $\mu\text{A}$ |
| $I_{LINI}$ | LIN logic "0" input bias current             | $LIN = 0\text{ V}$  |      |      | 1    | $\mu\text{A}$ |
| $I_{SDh}$  | $\overline{SD}$ logic "0" input bias current | $\overline{SD} = 15\text{ V}$                             | 30   | 120  | 300  | $\mu\text{A}$ |
| $I_{SDI}$  | $\overline{SD}$ logic "1" input bias current | $\overline{SD} = 0\text{ V}$                              |      |      | 3    | $\mu\text{A}$ |
| Dt         | Dead time                                    | see <a href="#">Figure 7</a> and <a href="#">Table 14</a> |      | 1.2  |      | $\mu\text{s}$ |

**Table 11. Sense comparator characteristics ( $V_{CC} = 15\text{ V}$  unless otherwise specified)**

| Symbol        | Parameter   | Test conditions  | Min. | Typ. | Max. | Unit               |
|---------------|---|--|------|------|------|--------------------|
| $I_{ib}$      | Input bias current                                    | $V_{CIN} = 1\text{ V}$   | -    |      | 3    | $\mu\text{A}$      |
| $V_{ol}$      | Open-drain low-level output voltage                   | $I_{od} = 3\text{ mA}$   | -    |      | 0.5  | V                  |
| $t_{d\_comp}$ | Comparator delay                                      | $\overline{SD}/OD$ pulled to 5 V through 100 k $\Omega$ resistor | -    | 90   | 130  | ns                 |
| SR            | Slew rate   | $C_L = 180\text{ pF}$ ; $R_{pu} = 5\text{ k}\Omega$              | -    | 60   |      | V/ $\mu\text{sec}$ |
| $t_{sd}$      | Shut down to high / low side driver propagation delay | $V_{OUT} = 0$ , $V_{boot} = V_{CC}$ ,<br>$V_{IN} = 0$ to 3.3 V   | 50   | 125  | 200  | ns                 |

**Table 12. Truth table**

| Condition                                   | Logic input ( $V_i$ ) |     |     | Output |     |
|---|-----------------------|-----|-----|--------|-----|
|   | $\overline{SD}$       | LIN | HIN | LVG    | HVG |
| Shutdown enable<br>half-bridge tri-state    | L                     | X   | X   | L      | L   |
| Interlocking<br>half-bridge tri-state       | H                     | H   | H   | L      | L   |
| 0 "logic state"<br>half-bridge tri-state    | H                     | L   | L   | L      | L   |
| 1 "logic state"<br>low side direct driving  | H                     | H   | L   | H      | L   |
| 1 "logic state"<br>high side direct driving | H                     | L   | H   | L      | H   |

Note: X: don't care

3.1.1 NTC thermistor

Table 13. NTC thermistor

| Symbol           | Parameter             | Test conditions  | Min. | Typ. | Max. | Unit. |
|------------------|-----------------------|------------------|------|------|------|-------|
| R <sub>25</sub>  | Resistance            | T = 25°C         |      | 4.7  |      | kΩ    |
| R <sub>125</sub> | Resistance            | T = 125°C        |      | 160  |      | Ω     |
| B                | B-constant            | T = 25°C to 85°C |      | 3950 |      | K     |
| T                | Operating temperature |                  | -40  |      | 150  | °C    |

Equation 1: resistance variation vs. temperature

$$R(T) = R_{25} \cdot e^{B \left( \frac{1}{T} - \frac{1}{298} \right)}$$

Where T are temperatures in Kelvins

Figure 7. NTC resistance vs. temperature

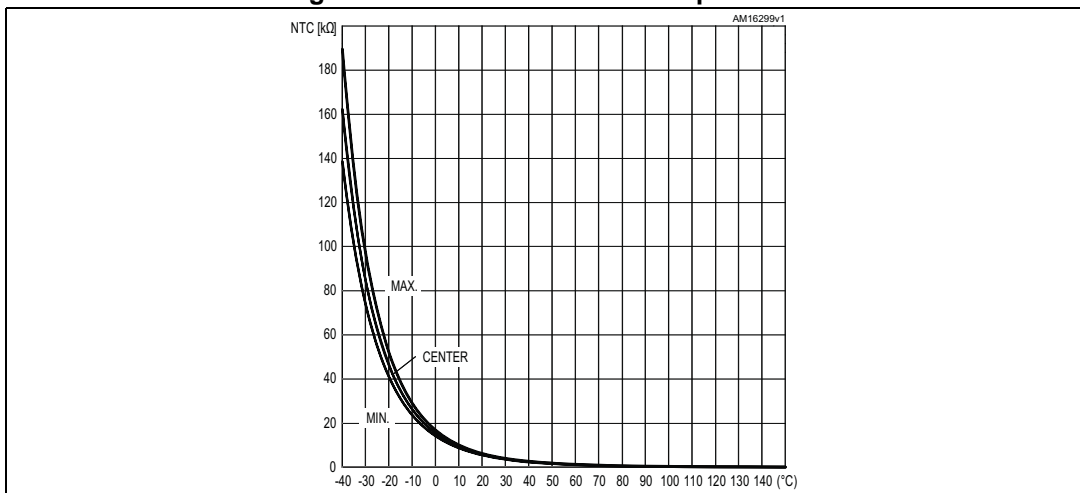
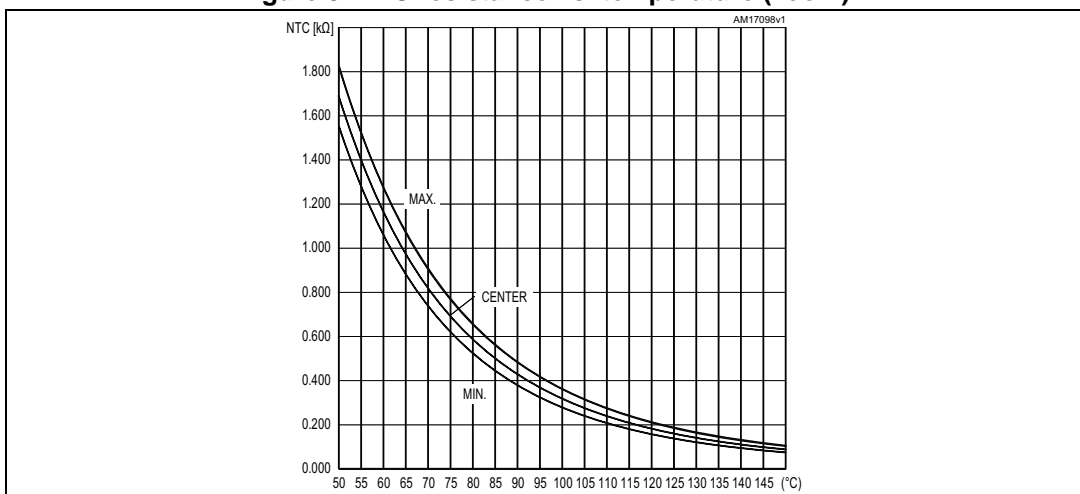
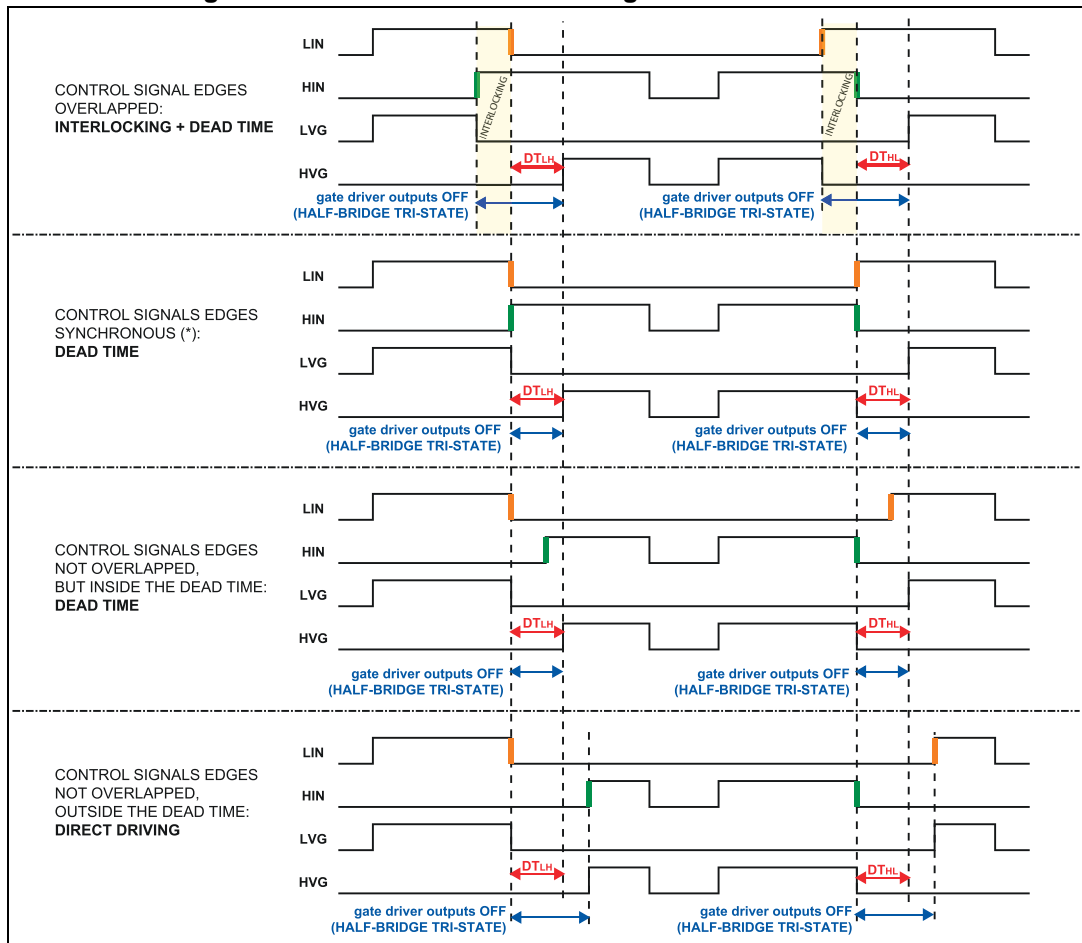


Figure 8. NTC resistance vs. temperature (zoom)



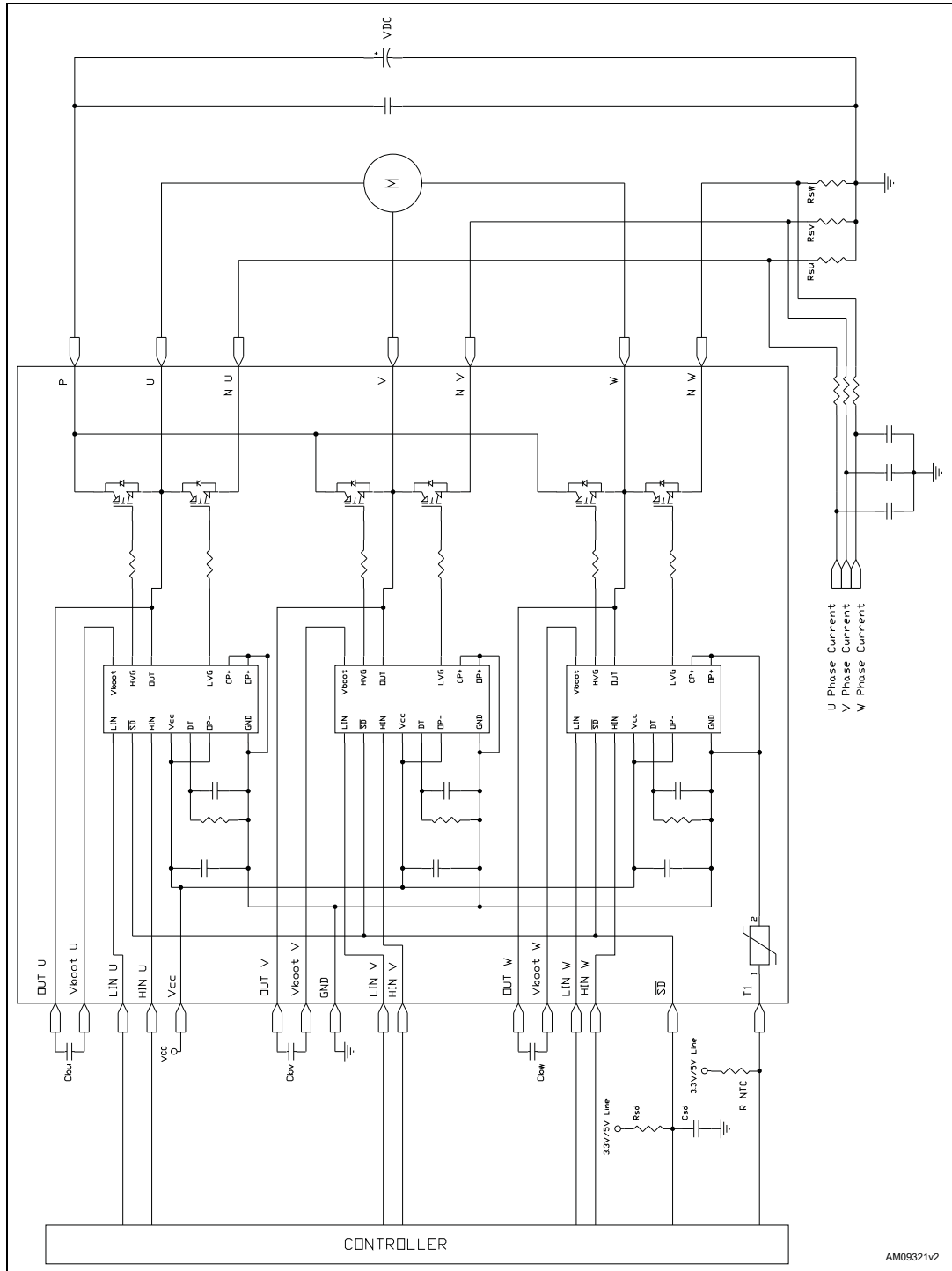
### 3.2 Waveform definitions

Figure 9. Dead time and interlocking waveforms definition



# 4 Application information

Figure 10. Typical application circuit



AM09321v2

## 4.1 Recommendations

- Input signals HIN, LIN are active high logic. A 375 k $\Omega$  (typ.) pull down resistor is built-in for each input. If an external RC filter is used, for noise immunity, pay attention to the variation of the input signal level.
- To prevent the input signals oscillation, the wiring of each input should be as short as possible.
- By integrating an application specific type HVIC inside the module, direct coupling to MCU terminals without any opto-coupler is possible.
- Each capacitor should be located as nearby the pins of IPM as possible.
- Low inductance shunt resistors should be used for phase leg current sensing.
- Electrolytic bus capacitors should be mounted as close to the module bus terminals as possible. Additional high frequency ceramic capacitor mounted close to the module pins will further improve performance.
- The  $\overline{SD}$  signal should be pulled up to 5 V / 3.3 V with an external resistor.

**Table 14. Recommended operating conditions**

| Symbol            | Parameter                          | Conditions   | Value |      |      | Unit    |
|-------------------|------------------------------------|--|-------|------|------|---------|
|                   |                                    |  | Min.  | Typ. | Max. |         |
| V <sub>PN</sub>   | Supply Voltage                     | Applied between P-Nu,Nv,Nw                                       |       | 300  | 400  | V       |
| V <sub>CC</sub>   | Control supply voltage             | Applied between V <sub>CC</sub> -GND                             | 13.5  | 15   | 18   | V       |
| V <sub>BS</sub>   | High side bias voltage             | Applied between V <sub>BOOTi</sub> -OUT <sub>i</sub> for i=U,V,W | 13    |      | 18   | V       |
| t <sub>dead</sub> | Blanking time to prevent Arm-short | For each input signal  | 1.5   |      |      | $\mu$ s |
| f <sub>PWM</sub>  | PWM input signal                   | -40°C < T <sub>c</sub> < 100°C<br>-40°C < T <sub>j</sub> < 125°C |       |      | 20   | kHz     |
| T <sub>C</sub>    | Case operation temperature         |  |       |      | 100  | °C      |

Note: For further details refer to AN3338.

## 5 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: [www.st.com](http://www.st.com). ECOPACK<sup>®</sup> is an ST trademark.

Please refer to dedicated technical note TN0107 for mounting instructions.

### 5.1 SDIP-25L package information

Figure 11. SDIP-25L package outline

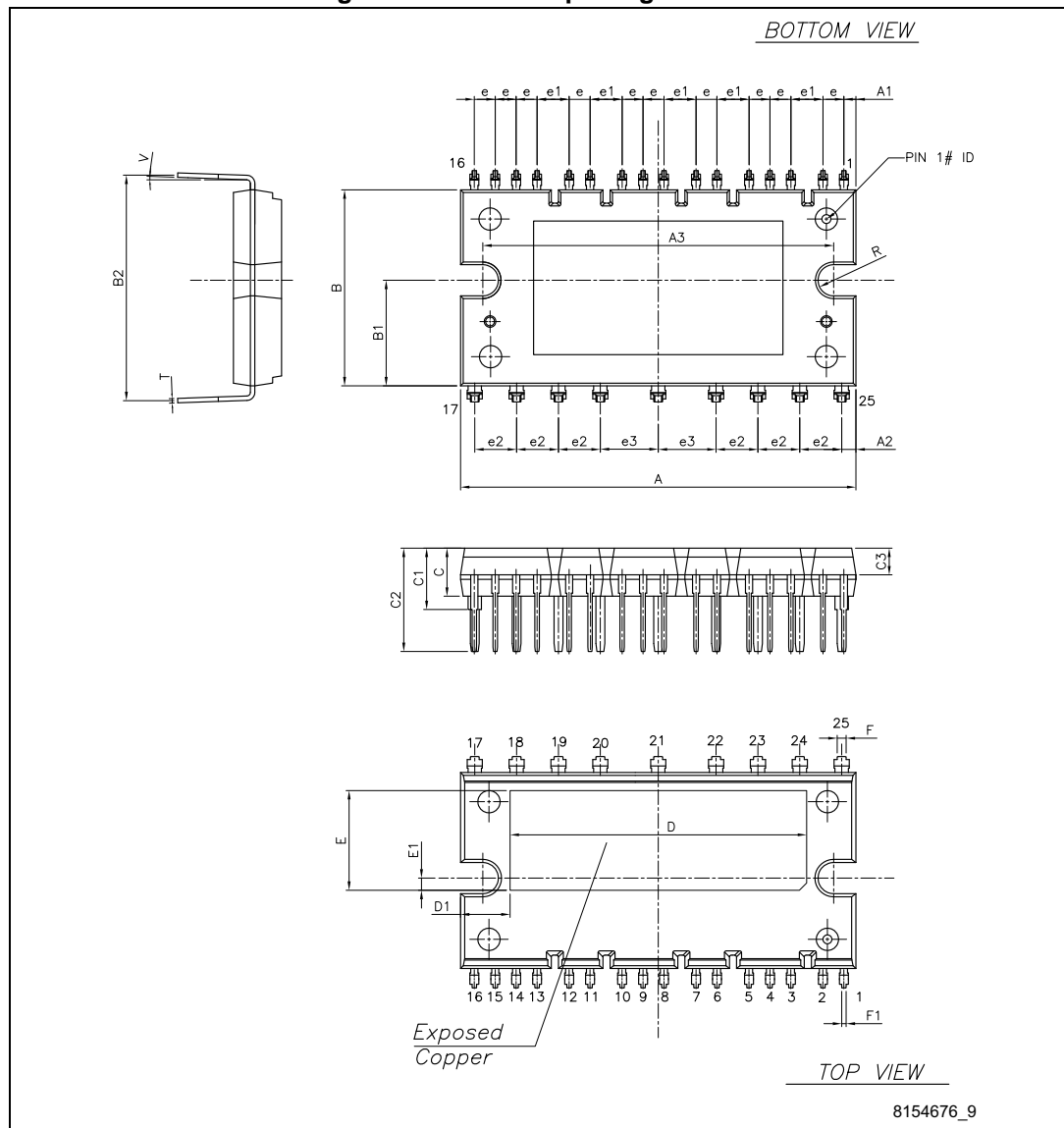


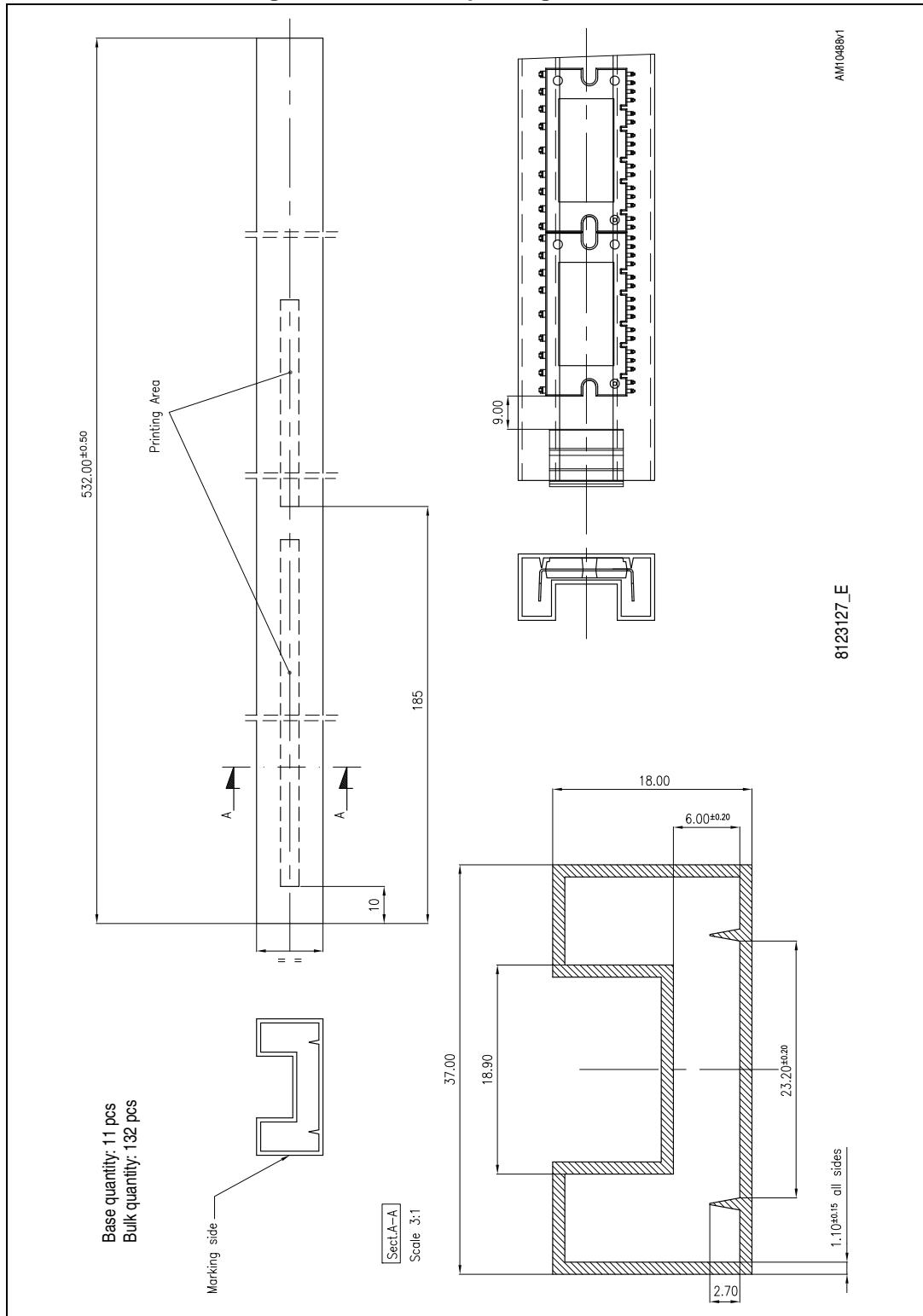
Table 15. SDIP-25L mechanical data

| Dim. | mm    |       |       |
|------|-------|-------|-------|
|      | Min.  | Typ.  | Max.  |
| A    | 43.90 | 44.40 | 44.90 |
| A1   | 1.15  | 1.35  | 1.55  |
| A2   | 1.40  | 1.60  | 1.80  |
| A3   | 38.90 | 39.40 | 39.90 |
| B    | 21.50 | 22.00 | 22.50 |
| B1   | 11.25 | 11.85 | 12.45 |
| B2   | 24.83 | 25.23 | 25.63 |
| C    | 5.00  | 5.40  | 6.00  |
| C1   | 6.50  | 7.00  | 7.50  |
| C2   | 11.20 | 11.70 | 12.20 |
| C3   | 2.90  | 3.00  | 3.10  |
| e    | 2.15  | 2.35  | 2.55  |
| e1   | 3.40  | 3.60  | 3.80  |
| e2   | 4.50  | 4.70  | 4.90  |
| e3   | 6.30  | 6.50  | 6.70  |
| D    |       | 33.30 |       |
| D1   |       | 5.55  |       |
| E    |       | 11.20 |       |
| E1   |       | 1.40  |       |
| F    | 0.85  | 1.00  | 1.15  |
| F1   | 0.35  | 0.50  | 0.65  |
| R    | 1.55  | 1.75  | 1.95  |
| T    | 0.45  | 0.55  | 0.65  |
| V    | 0°    |       | 6°    |



## 5.2 Packing information

Figure 12. SDIP-25L packing information



## 6 Revision history

Table 16. Document revision history

| Date        | Revision | Changes   |
|-------------|----------|---|
| 09-Oct-2014 | 1        | Initial release   |
| 10-Apr-2015 | 2        | Text edits and formatting changes throughout document<br>Updated <a href="#">Figure 2: Pin layout (bottom view)</a><br>Updated <a href="#">Section 5: Package information</a> |

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- Поставку компонентов в любых объемах, удовлетворяющих вашим потребностям.
- Приемлемые сроки поставки, возможна ускоренная поставка.
- Доставку товара в любую точку России и стран СНГ.
- Комплексную поставку.
- Работу по проектам и поставку образцов.
- Формирование склада под заказчика.
- Сертификаты соответствия на поставляемую продукцию (по желанию клиента).
- Тестирование поставляемой продукции.
- Поставку компонентов, требующих военную и космическую приемку.
- Входной контроль качества.
- Наличие сертификата ISO.

В составе нашей компании организован Конструкторский отдел, призванный помогать разработчикам, и инженерам.

Конструкторский отдел помогает осуществить:

- Регистрацию проекта у производителя компонентов.
- Техническую поддержку проекта.
- Защиту от снятия компонента с производства.
- Оценку стоимости проекта по компонентам.
- Изготовление тестовой платы монтаж и пусконаладочные работы.



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